







CD54HC4511, CD74HC4511, CD74HCT4511 SCHS279E - DECEMBER 1998 - REVISED AUGUST 2022

# CDx4HC4511, CD74HCT4511 BCD-to-7 Segment Latch/Decoder/Drivers

#### 1 Features

- 2-V to 6-V V<sub>CC</sub> operation ('HC4511)
- 4.5-V to 5.5-V V<sub>CC</sub> operation (CD74HCT4511)
- High-output sourcing capability
  - 7.5 mA at 4.5 V (CD74HCT4511)
  - 10 mA at 6 V ('HC4511)
- Input latches for BCD code storage
- Lamp test and blanking capability
- Balanced propagation delays and transition times
- Significant power reduction compared to LSTTL logic IC's
- 'HC4511
  - High noise immunity,  $N_{IL}$  or  $N_{IH}$  = 30% of  $V_{CC}$  at  $V_{CC}$  = 5 V
- CD74HCT4511
  - Direct LSTTL input logic compatibility, V<sub>IL</sub> = 0.8 V Maximum, V<sub>IH</sub> = 2 V minimum
  - CMOS input compatibility, I<sub>I</sub> ≤ 1<sub>µA</sub> at V<sub>OL</sub>, V<sub>OH</sub>

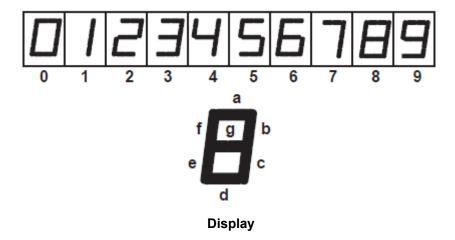
## 2 Description

The CD54HC4511, CD74HC4511, CD74HCT4511 are BCD-to-7 segment latch/decoder/ drivers with four address inputs (D<sub>0</sub>-D<sub>3</sub>), an activelow blanking  $(\overline{BL})$  input, lamp-test  $(\overline{LT})$  input, and a latch-enable (LE) input that, when high, enables the latches to store the BCD inputs. When LE is low, the latches are disabled, making the outputs transparent to the BCD inputs.

#### **Device Information**

PART NUMBER	PACKAGE <sup>(1)</sup>	BODY SIZE (NOM)
CD54HC4511	J (CDIP, 16)	24.38 mm × 6.92 mm
CD74HC4511	N (PDIP, 16)	19.31 mm × 6.35 mm
	D (SOIC, 16)	9.90 mm × 3.90 mm
	PW (TSSOP, 16)	5.00 mm × 4.40 mm
CD74HCT4511	N (PDIP, 16)	19.31 mm × 6.35 mm

For all available packages, see the orderable addendum at the end of the data sheet.





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# 3 Revision History

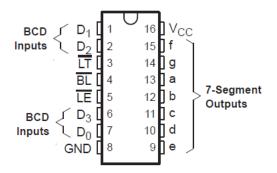
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

#### Changes from Revision D (October 2003) to Revision E (August 2022)

**Page** 



# **4 Pin Configuration and Functions**



J, N, D, PW package 16-Pin CDIP, PDIP, SOIC, TSSOP Top View



## **5 Specifications**

#### **5.1 Absolute Maximum Ratings**

over operating free-air temperature (unless otherwise noted)(1)

-	·	·	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		- 0.5	7	V
I <sub>IK</sub>	Input diode current	$V_1 < -0.5 \text{ V or } V_1 > V_{CC} + 0.5 \text{ V}^{(1)}$		±20	mA
I <sub>OK</sub>	Output diode current	$V_{\rm O}$ < $-0.5$ V or $V_{\rm O}$ > $V_{\rm CC}$ + $0.5$ V <sup>(1)</sup>		±20	mA
Io	Output source or sink current per output pin	$V_O = 0$ to $V_{CC}$		±25	mA
	Continuous current through V <sub>CC</sub> or GND			±50	mA
TJ	Junction temperature			150	°C
T <sub>stg</sub>	Storage temperature range		<b>–</b> 65	150	°C
		At distance 1/16 ± 1/32 in (1.59 ± 0.79 mm) from case for 10 s maximum		265	°C
	Lead temperature (During Soldering)	Unit inserted into a PC board (minimum thickness 1/16 in, 1.59 mm) (with solder contacting lead tips only)		300	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability

# 5.2 Recommended Operating Conditions for 'HC4511<sup>(1)</sup>

			T <sub>A</sub> = 2	5°C	T <sub>A</sub> = - 55		T <sub>A</sub> = - 40°C to 85°C		UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	
V <sub>CC</sub>	Supply voltage		2	6	2	6	2	6	V
		V <sub>CC</sub> = 2 V	1.5		1.5		1.5		
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 4.5 V	3.15		3.15		3.15		V
		V <sub>CC</sub> = 6 V	4.2		4.2		4.2		
		V <sub>CC</sub> = 2 V		0.5		0.5		0.5	
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 4.5 V		1.35		1.35		1.35	V
		V <sub>CC</sub> = 6 V		1.8		1.8		1.8	
VI	Input voltage		0	V <sub>CC</sub>	0	V <sub>CC</sub>	0	V <sub>CC</sub>	V
Vo	Output voltage		0	V <sub>CC</sub>	0	V <sub>CC</sub>	0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 2 V		1000		1000		1000	
t <sub>t</sub>	Input transition rise/fall time	V <sub>CC</sub> = 4.5 V		500		500		500	ns
		V <sub>CC</sub> = 6 V		400		400		400	

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report Implications of Slow or Floating SMOS Inputs, literature number SCBA004.

#### 5.3 Recommended Operating Conditions for CD74HCT4511<sup>(1)</sup>

		T <sub>A</sub> = - 55°C	to 125°C	T <sub>A</sub> = - 55°C 1	to 125°C	T <sub>A</sub> = - 40°C	to 85°C	UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	ONII
V <sub>CC</sub>	Supply Voltage	4.5	5.5	4.5	5.5	4.5	5.5	V
V <sub>IH</sub>	High-level input voltage	2		2		2		V
V <sub>IL</sub>	Low-level input voltage		0.8		0.8		0.8	
VI	Input voltage		V <sub>CC</sub>		V <sub>CC</sub>		V <sub>CC</sub>	V
Vo	Output voltage		V <sub>CC</sub>		V <sub>CC</sub>		V <sub>CC</sub>	V



# 5.3 Recommended Operating Conditions for CD74HCT4511<sup>(1)</sup> (continued)

		$T_A = -55^{\circ}C$	to 125°C	$T_A = -55^{\circ}C$	to 125°C	$T_A = -40^\circ$	C to 85°C	UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	ONII
t <sub>t</sub>	Input transition (rise and fall) time		500		500		500	ns

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report Implications of Slow or Floating SMOS Inputs, literature number SCBA004.

#### **5.4 Thermal Information**

		D (SOIC)	N (PDIP)	PW (TSSOP)	
THERMAL ME	TRIC <sup>(1)</sup>	16 PINS	16 PINS	16 PINS	UNIT
$R_{\theta JA}$	Package thermal impedance	67	73	108	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.

#### 5.5 'HC4511 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CO	NDITIONS	V <sub>cc</sub>	T <sub>A</sub> = 2	25°C	T <sub>A</sub> = - 55°C to 125°C		T <sub>A</sub> = - 40°C to 85°C		UNIT	
					MIN	MAX	MIN	MAX	MIN	MAX		
				2 V	1.9		1.9		1.9			
			I <sub>OH</sub> = -20 μA	4.5 V	4.4		4.4		4.4			
V <sub>OH</sub>	High level output voltage			6 V	5.9		5.9		5.9		V	
			I <sub>OH</sub> = -4 mA	4.5 V	3.98		3.7		3.84			
			I <sub>OH</sub> = −5.2 mA	6 V	5.48		5.2		5.34			
				2 V		0.1		0.1		0.1		
					I <sub>OL</sub> = 20 μA	4.5 V		0.1		0.1		0.1
V <sub>OL</sub>	Low level output voltage	$V_I = V_{IH}$ or $V_{IL}$		6 V		0.1		0.1		0.1	V	
				I <sub>OL</sub> = 4 mA	4.5 V		0.26		0.4	,	0.33	
			I <sub>OL</sub> = 5.2 mA	6 V		0.26		0.4		0.33		
II	Input leakage current V	$V_I = V_{CC}$ or 0		6 V		±0.1		±1		±1	μΑ	
I <sub>CC</sub>	Supply current	$V_I = V_{CC}$ or 0,	I <sub>O</sub> = 0	6 V		8		160		80	μΑ	
C <sub>i</sub>	Input Capacitance			2 V to 6 V		10		10		10	pF	

#### 5.6 CD74HCT4511 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS		V <sub>CC</sub>	T <sub>A</sub> = 25°C		T <sub>A</sub> = -55°C to 125°C		T <sub>A</sub> = - 40°C to 85°C		UNIT	
					MIN	TYP	MAX	MIN	MAX	MIN	MAX	
V <sub>OH</sub>	High level output	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -20 μA	4.5 V	4.4			4.4		4.4		
VOH	voltage	VI - VIH OI VIL	I <sub>OH</sub> = -4 mA	4.5 V	3.98			3.7		3.84		V
V	Low level output	$V_I = V_{IH}$ or $V_{IL}$	I <sub>OL</sub> = 20 μA	4.5 V			0.1		0.1		0.1	, <b>'</b>
V <sub>OL</sub>	voltage	VI - VIH OI VIL	I <sub>OL</sub> = 4 mA	4.5 V			0.26		0.4		0.33	
I <sub>1</sub>	Input leakage current V	V <sub>I</sub> = V <sub>CC</sub> to GND		5.5 V			±0.1		±1		±1	μΑ
I <sub>CC</sub>	Supply current	$V_I = V_{CC}$ or 0,	I <sub>O</sub> = 0	5.5 V			8		160		80	μA
(1)	Supply-Current	TT, LE inputs held at V <sub>CC</sub> – 2.1 V		4.5 V		100	540		735		675	
ΔI <sub>CC</sub> (1)	Change  Supply-Current  Change  BL, Dn inputs held		l at V <sub>CC</sub> – 2.1 V	to 5.5 V		100	108		147		135	μA



## **5.6 CD74HCT4511 Electrical Characteristics (continued)**

over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	T <sub>A</sub> = 25°C		T <sub>A</sub> = -55°C to 125°C		T <sub>A</sub> = - 40°C to 85°C		UNIT	
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
Ci	Input Capacitance					10		10		10	pF

<sup>(1)</sup> Additional supply current per input pin, TTL inputs high, 1 unit load. For dual-supply systems, theoretical worst-case (V<sub>I</sub> = 2.4 V, V<sub>CC</sub> = 5.5 V) specification is 1.8 mA.

# 5.7 'HC4511 Timing Requirements

	,	V <sub>cc</sub>	T <sub>A</sub> = 25	s°C	T <sub>A</sub> = - 55° 125°C		T <sub>A</sub> = - 40 85°C		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
		2 V	80		120		100		
t <sub>W</sub>	Pulse duration, LE low	4.5 V	16		24		20		ns
		6 V	14		20		17		
		2 V	60		90		75		
t <sub>su</sub>	Setup time, BCD inputs before $\overline{\text{LE}}$ ↑	4.5 V	12		18		15		ns
		6 V	10		15		13		
			3		3		3		
t <sub>h</sub> H	Hold time, BCD inputs before LE↑	4.5 V	3		3		3		ns
		6 V	3		3		3		

# **5.8 Switching Characteristics**

PARAMETER	FROM	то	LOAD	V <sub>CC</sub>	-	T <sub>A</sub> = 25°C	;	T <sub>A</sub> = - 55°C TO 125°C	T <sub>A</sub> = - 40°C TO 85°C	UNIT	
	(INPUT)	(OUTPUT)	CAPACITANCE		MIN	TYP	MAX	MIN MAX	MIN MAX		
				2 V			300	450	375		
	D <sub>n</sub>	Output	C <sub>L</sub> = 50 pF	4.5 V			60	90	75		
	D <sub>n</sub>	Output		6 V			51	77	64		
			C <sub>L</sub> = 15 pF	5 V		25					
				2 V			270	405	340		
	ĪĒ	Output	C <sub>L</sub> = 50 pF	4.5 V			54	81	68		
<b>f</b> .				6 V			46	69	58		
			C <sub>L</sub> = 15 pF	5 V		23					
t <sub>pd</sub>	BL Output			2 V			220	330	275	ns	
		Output	C <sub>L</sub> = 50 pF	4.5 V			44	66	55		
	DL	Output		6 V			37	56	47		
			C <sub>L</sub> = 15 pF	5 V		18					
				2 V			160	240	200		
	ΙΤ	Output	C <sub>L</sub> = 50 pF	4.5 V			32	48	40		
	LI	Output		6 V			27	41	34		
			C <sub>L</sub> = 15 pF	5 V		13					
				2 V			75	110	95		
t <sub>t</sub>	Any	Any C <sub>L</sub> = 50 pF 4	Any C <sub>L</sub> =	Any C <sub>L</sub> = 50 pF	4.5 V			15	22	19	ns
				6 V			13	19	16		



# 5.9 CD74HCT4511 Timing Requirements

			$T_A = 25^{\circ}C$ $T_A = -55^{\circ}C \text{ TO } 125$ $T_A = -40^{\circ}C \text{ TO } 8$		TO 85°C	UNIT		
		MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>w</sub>	Pulse duration, LE low	16		24		20		ns
t <sub>su</sub>	Setup time, BCD inputs before LE↑	16		24		20		ns
t <sub>h</sub>	Hold time, BCD inputs before LE↑	5		5		5		ns

over operating free-air temperature range (unless otherwise noted)

# 5.10 CD74HCT4511 Switching Characteristics

PARAMETER	FROM (INPUT)	TO	LOAD CAPACITANCE	V <sub>cc</sub>	T <sub>A</sub> = 25°C		T <sub>A</sub> = - 55°C to 125°C		T <sub>A</sub> = -40°C to 85°C		UNIT	
	(INPUT)	(OUTPUT)	CAPACITANCE		MIN	TYP	MAX	MIN	MAX	MIN	MAX	
	D <sub>n</sub>	Output	C <sub>L</sub> = 50 pF	4.5 V			60		90		75	
			C <sub>L</sub> = 15 pF	5 V		25						
	ΙĒ	Output	C <sub>L</sub> = 50 pF	4.5 V			54		81		68	
4			C <sub>L</sub> = 15 pF	5 V		23						no
t <sub>pd</sub>	BL	Output	C <sub>L</sub> = 50 pF	4.5 V			44		66		55	ns
			C <sub>L</sub> = 15 pF	5 V		18						
	ΙΤ	Output	C <sub>L</sub> = 50 pF	4.5 V			33		50		41	
			C <sub>L</sub> = 15 pF	5 V		13						
t <sub>t</sub>		Any	C <sub>L</sub> = 50 pF	4.5 V			15		22		19	ns

# **5.11 Operating Characteristics**

	PARAMETER <sup>(1)</sup>		TYP	UNIT
C	Power dissipation capacitance	'HC4511	114	pF
Opd		CD74HCT4511	110	ρг

 $<sup>\</sup>mathbf{C}_{\mathrm{pd}}$  is used to determine the dynamic power consumption, per package.

 $P_D = C_{pd}V_{CC}^2 f_i + \Sigma C_L V_{CC}^2 f_o$  where:  $f_i = \text{input frequency}$ 

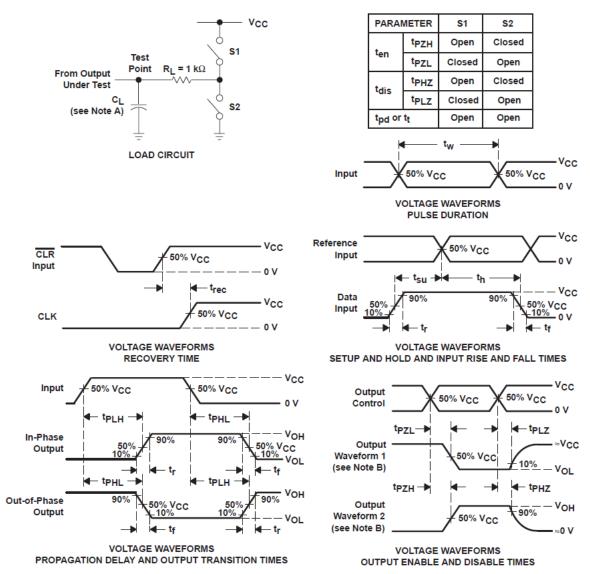
f<sub>o</sub> = output frequency

C<sub>L</sub> = output load capacitance

V<sub>CC</sub> = supply voltage



#### **6 Parameter Measurement Information**

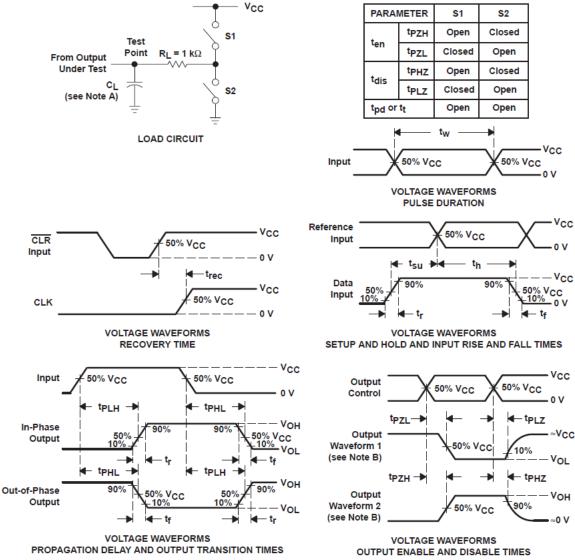


NOTES: A. C<sub>L</sub> includes probe and test-fixture capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O = 50 \Omega$ ,  $t_f = 6$  ns,  $t_f = 6$  ns.
- D. For clock inputs, f<sub>max</sub> is measured with the input duty cycle at 50%.
- E. The outputs are measured one at a time with one input transition per measurement.
- F. tpLZ and tpHZ are the same as tdis.
- G. tpzL and tpzH are the same as ten.
- H. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 6-1. 'HC4511





- NOTES: A. C<sub>L</sub> includes probe and test-fixture capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O = 50 \ \Omega$ ,  $t_r = 6 \ ns$ ,  $t_f = 6 \ ns$ .
  - D. For clock inputs, f<sub>max</sub> is measured with the input duty cycle at 50%.
  - E. The outputs are measured one at a time with one input transition per measurement.
  - F. tpLz and tpHz are the same as tdis.
  - G. tpzL and tpzH are the same as ten.
  - H. tpLH and tpHL are the same as tpd.

Figure 6-2. CD74HCT4511



## 7 Detailed Description

#### 7.1 Overview

The CD54HC4511, CD74HC4511, and CD74HCT4511 are BCD-to-7 segment latch/decoder/drivers with four address inputs ( $D_0$ – $D_3$ ), an active-low blanking ( $\overline{BL}$ ) input, lamp-test ( $\overline{LT}$ ) input, and a latch-enable ( $\overline{LE}$ ) input that, when high, enables the latches to store the BCD inputs. When  $\overline{LE}$  is low, the latches are disabled, making the outputs transparent to the BCD inputs.

These devices have standard-size output transistors, but are capable of sourcing (at standard  $V_{OH}$  levels) up to 7.5 mA at 4.5 V. The HC types can supply up to 10 mA at 6 V.

#### 7.2 Functional Block Diagram

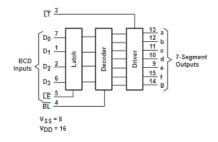


Figure 7-1. Function Diagram

#### 7.3 Device Functional Modes

**Table 7-1. Function Table** 

		ı	NPUTS <sup>(1</sup>	)						OU <sup>-</sup>	ΓΡUTS <sup>(2)</sup>			
LE	BL	ΙΤ	D <sub>3</sub>	D <sub>2</sub>	D <sub>1</sub>	D <sub>0</sub>	а	b	С	d	е	f	g	DISPLAY
Х	Х	L	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	8
Х	L	Н	Х	Х	Х	Х	L	L	L	L	L	L	L	Blank
L	Н	Н	L	L	L	L	Н	Н	Н	Н	Н	Н	L	0
L	Н	Н	L	L	L	Н	L	Н	Н	L	L	L	L	1
L	Н	Н	L	L	Н	L	Н	Н	L	Н	Н	L	Н	2
L	Н	Н	L	L	Н	Н	Н	Н	Н	Н	L	L	Н	3
L	Н	Н	L	Н	L	L	L	Н	Н	L	L	Н	Н	4
L	Н	Н	L	Н	L	Н	Н	L	Н	Н	L	Н	Н	5
L	Н	Н	L	Н	Н	L	L	L	Н	Н	Н	Н	Н	6
L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	L	L	L	7
L	Н	Н	Н	L	L	L	Н	Н	Н	Н	Н	Н	Н	8
L	Н	Н	Н	L	L	Н	Н	Н	Н	L	L	Н	Н	9
L	Н	Н	Н	L	Н	L	L	L	L	L	L	L	L	Blank
L	Н	Н	Н	L	Н	Н	L	L	L	L	L	L	L	Blank
L	Н	Н	Н	Н	L	L	L	L	L	L	L	L	L	Blank
L	Н	Н	Н	Н	L	Н	L	L	L	L	L	L	L	Blank
L	Н	Н	Н	Н	Н	L	L	L	L	L	L	L	L	Blank
L	Н	Н	Н	Н	Н	Н	L	L	L	L	L	L	L	Blank
Н	Н	Н	X	X	Х	X	t	t	t	t	t	t	t	t

<sup>(1)</sup> H = High Voltage Level, L = Low Voltage Level, X = Don't caret = Depends on BCD code previously applied when  $\overline{\text{LE}}$  = LNOTE: Display is blank for all illegal input codes (BCD > HLLH).

<sup>(2)</sup> H = Driving High, L = Driving Low, Z = High Impedance State



# 8 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. A 0.1- $\mu$ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1- $\mu$ F and 1- $\mu$ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

## 9 Layout

#### 9.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or  $V_{CC}$ , whichever makes more sense for the logic function or is more convenient.



# 10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

## 10.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 10.2 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 10.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

#### 10.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 10.5 Glossary

TI Glossary

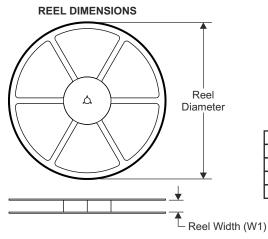
This glossary lists and explains terms, acronyms, and definitions.

## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



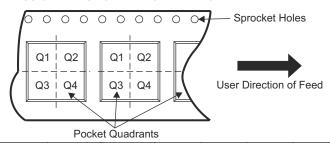
# 11.1 Tape and Reel Information



# TAPE DIMENSIONS KO P1 BO W Cavity A0

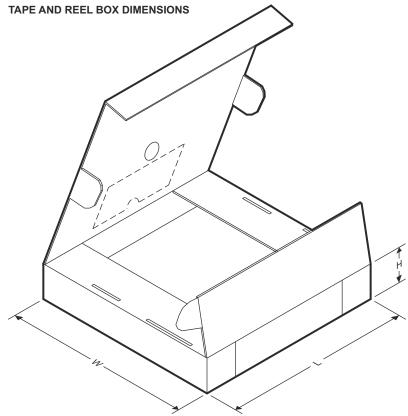
	D: 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



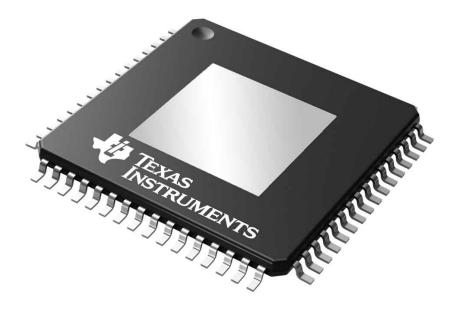
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
PTAS6584QDKQQ1	HTQFP	PHD	64	1000	330.0	24.4	17.0	17.0	1.5	20.0	24.0	Q2





Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
PTAS6584QPHDRQ1	HTQFP	PHD	64	1000	350.0	350.0	43.0

# 11.2 Mechanical Data



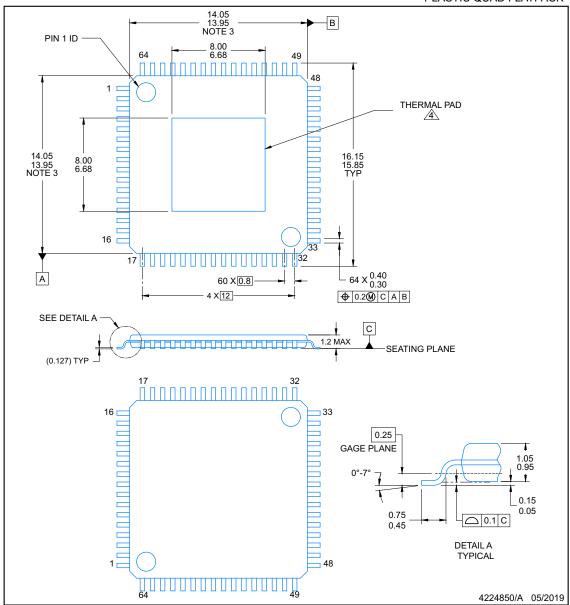


#### PACKAGE OUTLINE

# **PHD0064B**

## HTQFP - 1.2 mm max height

PLASTIC QUAD FLATPACK



- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per side.
- See technical brief. PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004) for information regarding recommended board layout.

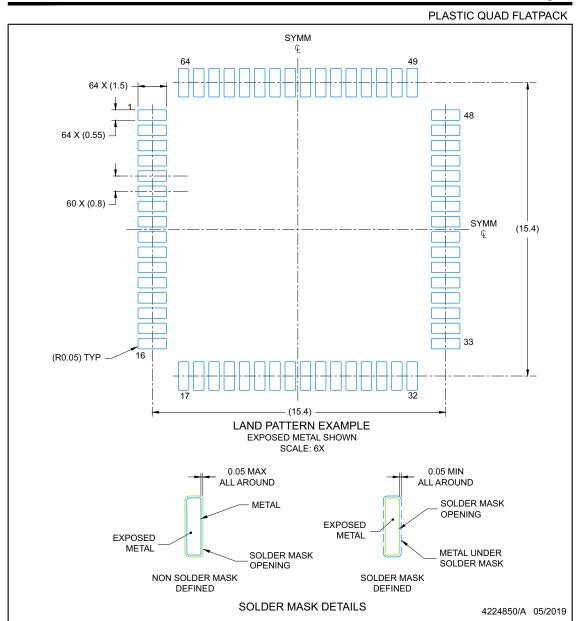




#### **EXAMPLE BOARD LAYOUT**

# PHD0064B

HTQFP - 1.2 mm max height



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.



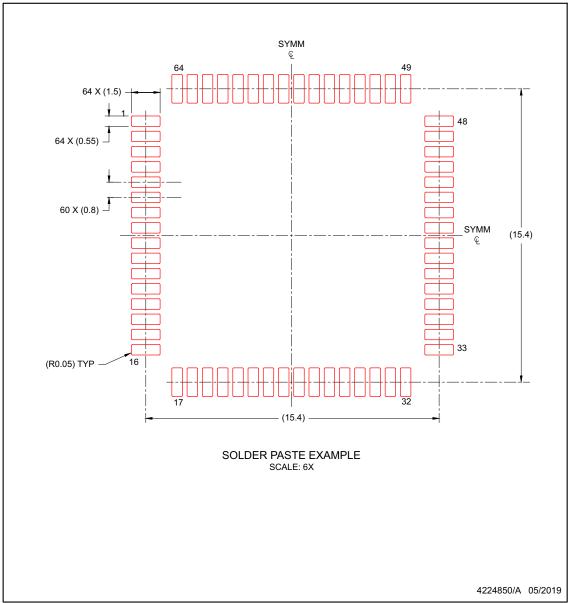


#### **EXAMPLE STENCIL DESIGN**

# PHD0064B

# HTQFP - 1.2 mm max height

PLASTIC QUAD FLATPACK



NOTES: (continued)

- Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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#### **PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
5962-8773301EA	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8773301EA CD54HC4511F3A
CD54HC4511F3A	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8773301EA CD54HC4511F3A
CD54HC4511F3A.A	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8773301EA CD54HC4511F3A
CD74HC4511E	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HC4511E
CD74HC4511E.A	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HC4511E
CD74HC4511EE4	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HC4511E
CD74HC4511M	Obsolete	Production	SOIC (D)   16	-	-	Call TI	Call TI	-55 to 125	HC4511M
CD74HC4511M96	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-55 to 125	HC4511M
CD74HC4511M96.A	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4511M
CD74HC4511M96G4	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4511M
CD74HC4511M96G4.A	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4511M
CD74HC4511PWR	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4511
CD74HC4511PWR.A	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4511
CD74HC4511PWRE4	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4511
CD74HC4511PWRG4	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4511
CD74HC4511PWT	Obsolete	Production	TSSOP (PW)   16	-	-	Call TI	Call TI	-55 to 125	HJ4511
CD74HCT4511E	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HCT4511E
CD74HCT4511E.A	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HCT4511E

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

# **PACKAGE OPTION ADDENDUM**

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(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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#### OTHER QUALIFIED VERSIONS OF CD54HC4511, CD74HC4511:

Catalog: CD74HC4511

Military: CD54HC4511

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

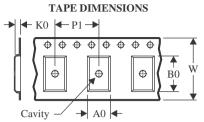
• Military - QML certified for Military and Defense Applications

# **PACKAGE MATERIALS INFORMATION**

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#### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC4511M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC4511M96G4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC4511PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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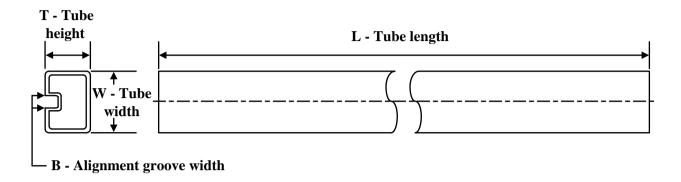
#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC4511M96	SOIC	D	16	2500	353.0	353.0	32.0
CD74HC4511M96G4	SOIC	D	16	2500	353.0	353.0	32.0
CD74HC4511PWR	TSSOP	PW	16	2000	353.0	353.0	32.0

# **PACKAGE MATERIALS INFORMATION**

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#### **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD74HC4511E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC4511E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC4511E.A	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC4511E.A	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC4511EE4	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC4511EE4	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT4511E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT4511E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT4511E.A	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT4511E.A	N	PDIP	16	25	506	13.97	11230	4.32

# D (R-PDS0-G16)

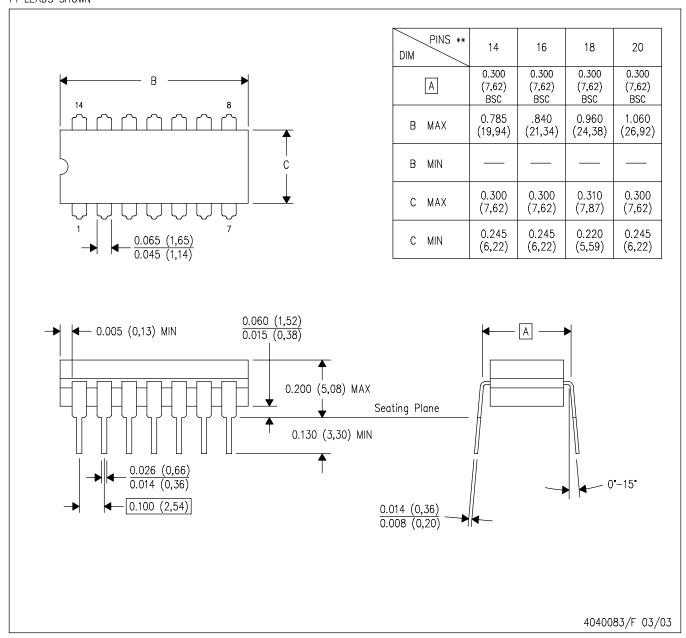
# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



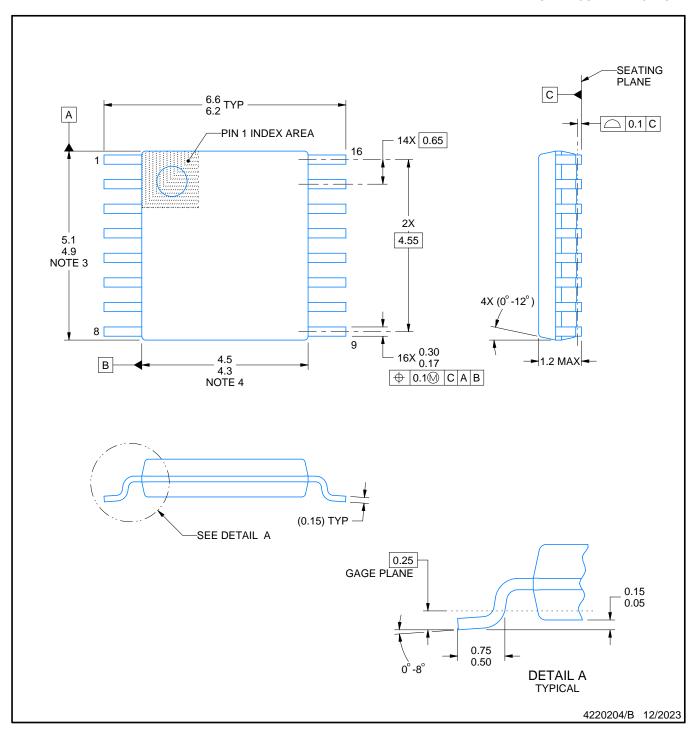
#### 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.



SMALL OUTLINE PACKAGE



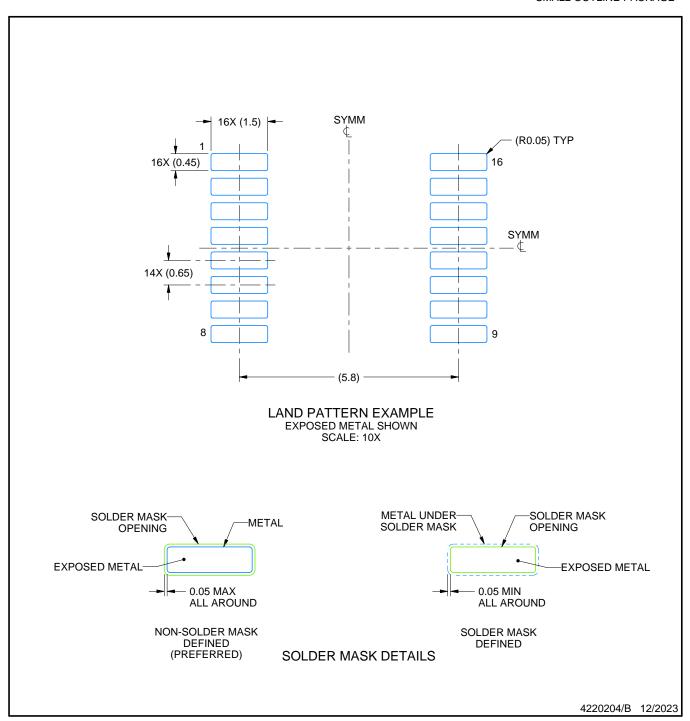
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE

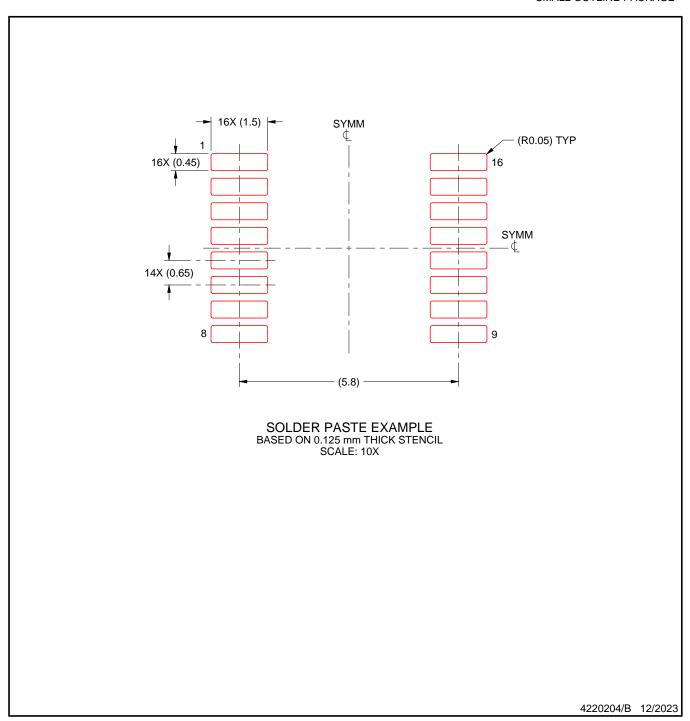


NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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